N-Channel Silicon MOSFET



2SK1426

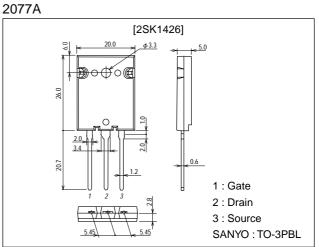
Ultrahigh-Speed Switching Applications

Features

- · Low ON-state resistance.
- · Ultrahigh-speed switching.
- \cdot Converters.

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		60	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	۱ _D		100	A
Drain Current (Pulse)	I _{DP}	PW≤10µs, duty cycle≤1%	400	A
Allowable Power Dissipation	P-	Tc=25°C	200	W
	PD		3.5	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Symbol	Conditions	Ratings			Unit
		min	typ	max	Unit
V(BR)DSS	I _D =1mA, V _{GS} =0	60			V
IDSS	V _{DS} =60V, V _{GS} =0			100	μΑ
IGSS	V _{GS} =±20V, V _{DS} =0			±100	nA
VGS(off)	V _{DS} =10V, I _D =1mA	1.5		2.5	V
yfs	V _{DS} =10V, I _D =60A	40	70		S
R _{DS(on)}	I _D =60A, V _{GS} =10V		0.008	0.012	Ω
	V _{(BR)DSS} I _{DSS} I _{GSS} V _{GS(off)} yfs	V(BR)DSS ID=1mA, VGS=0 IDSS VDS=60V, VGS=0 IGSS VGS=±20V, VDS=0 VGS(off) VDS=10V, ID=1mA yfs VDS=10V, ID=60A	V(BR)DSS ID=1mA, VGS=0 60 IDSS VDS=60V, VGS=0 1000000000000000000000000000000000000	Symbol Conditions min typ V(BR)DSS ID=1mA, VGS=0 60 60 IDSS VDS=60V, VGS=0 60 60 IGSS VGS=±20V, VDS=0 60 60 VGS(off) VDS=10V, ID=1mA 1.5 1.5 yfs VDS=10V, ID=60A 40 70	Symbol Conditions min typ max V(BR)DSS ID=1mA, VGS=0 60 100 IDSS VDS=60V, VGS=0 100 100 IGSS VGS=±20V, VDS=0 ±100 ±100 VGS(off) VDS=10V, ID=1mA 1.5 2.5 I yfs I VDS=10V, ID=60A 40 70

(Note) Be careful in handling the 2SK1426 because it has no protection diode between gate and source.

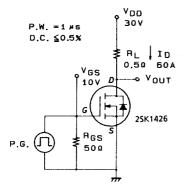
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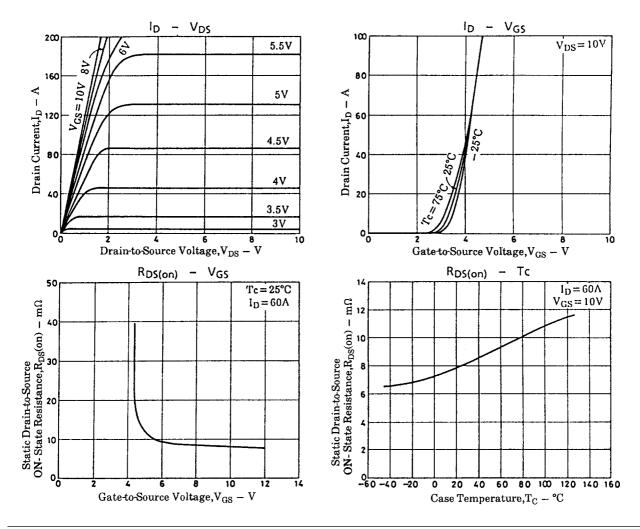
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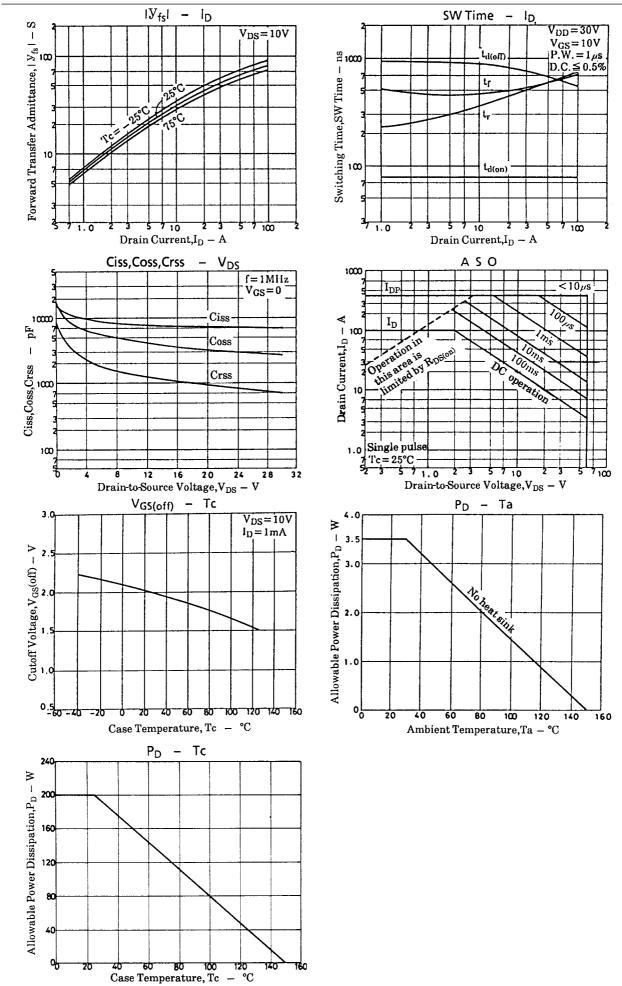
Parameter	Symbol	Conditions	Ratings			Unit
Falantelei			min	typ	max	Unit
Input Capacitance	Ciss	V _{DS} =20V, f=1MHz		7200		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		3300		pF
Reverse Transfer Capacitance	Crss	V _{DS} =20V, f=1MHz		900		pF
Turn-ON Delay Time	t _{d(on)}	I_{D} =60A, V_{GS} =10V, V_{DD} =30V, R_{GS} =50 Ω		78		ns
Rise Time	tr	I _D =60A, V _{GS} =10V, V _{DD} =30V, R _{GS} =50Ω		622		ns
Turn-OFF Delay Time	td(off)	I _D =60A, V _{GS} =10V, V _{DD} =30V, R _{GS} =50Ω		650		ns
Fall Time	tf	I _D =60A, V _{GS} =10V, V _{DD} =30V, R _{GS} =50Ω		600		ns
Diode Forward Voltage	V _{SD}	I _S =100A, V _{GS} =0			1.8	V

Switching Time Test Circuit





No.3564-2/4



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